



LF412-N Low Offset, Low Drift Dual JFET Input Operational Amplifier

1 Features

- Internally Trimmed Offset Voltage: 1 mV (Max)
- Input Offset Voltage Drift: 7 $\mu\text{V}/^\circ\text{C}$ (Typ)
- Low Input Bias Current: 50 pA
- Low Input Noise Current: 0.01 pA / $\sqrt{\text{Hz}}$
- Wide Gain Bandwidth: 3 MHz (Min)
- High Slew Rate: 10V/ μs (Min)
- Low Supply Current: 1.8 mA/Amplifier
- High Input Impedance: $10^{12}\Omega$
- Low Total Harmonic Distortion: $\leq 0.02\%$
- Low 1/f Noise Corner: 50 Hz
- Fast Settling Time to 0.01%: 2 μs

2 Applications

- High Speed Integrators
- Fast D/A Converters
- Sample and Hold Circuits

3 Description

These devices are low cost, high speed, JFET input operational amplifiers with very low input offset voltage and input offset voltage drift. They require low supply current yet maintain a large gain bandwidth product and fast slew rate. In addition, well matched high voltage JFET input devices provide very low input bias and offset currents. The LF412-N dual is pin compatible with the LM1558, allowing designers to immediately upgrade the overall performance of existing designs.

These amplifiers may be used in applications such as high speed integrators, fast D/A converters, sample and hold circuits and many other circuits requiring low input offset voltage and drift, low input bias current, high input impedance, high slew rate and wide bandwidth.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LF412ACN	PDIP	9.59 mm x 6.35 mm
LF412CN	PDIP	9.59 mm x 6.35 mm
LF412MH	TO	9.14 mm diameter

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Inverting Amplifier

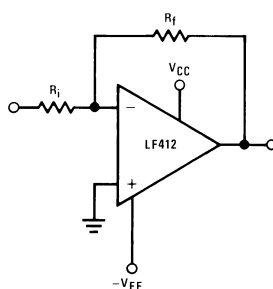


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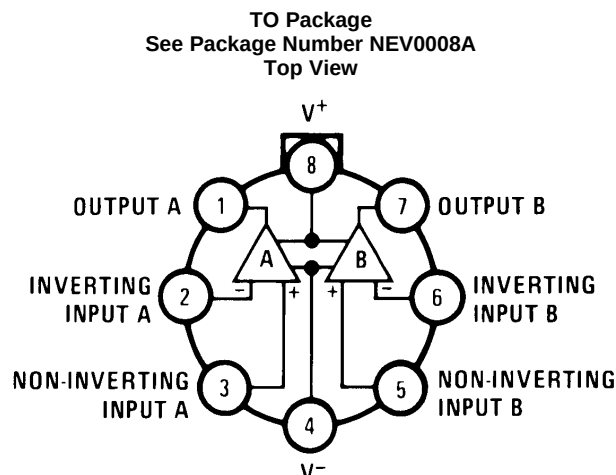
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (March 2014) to Revision F	Page
• Updated datasheet to new TI layout	1
• Deleted note.	5
• Deleted $\Delta V_{OS}/\Delta T$ Max specification for LF412A.	5
• Deleted $\Delta V_{OS}/\Delta T$ Max specification for LF412.	5
• Added Application Note	14

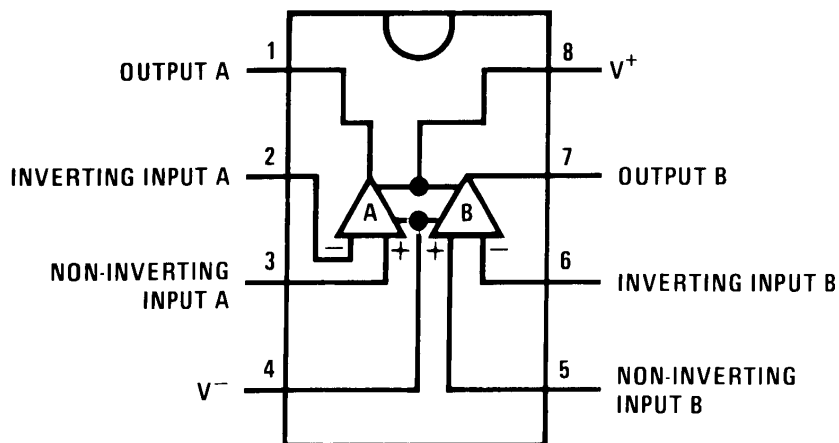
Changes from Revision D (March 2013) to Revision E	Page
• Changed layout of National Data Sheet to TI format	14

5 Pin Configuration and Functions



Note. Pin 4 connected to case.

PDIP/CDIP Package
See Package Number P0008E or NAB0008A
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
Output A	1	O	Amplifier A Output
Inverting Input A	2	I	Amplifier A Inverting Input
Non-Inverting Input A	3	I	Amplifier A Non-Inverting Input
V-	4	P	Negative Supply
Non-Inverting Input B	5	I	Amplifier B Non-Inverting Input
Inverting Input B	6	I	Amplifier B Inverting Input
Output B	7	O	Amplifier B Output
V+	8	P	Positive Supply

6 Specifications

6.1 Absolute Maximum Ratings

 over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

	LF412A		LF412		UNIT
	MIN	MAX	MIN	MAX	
Supply Voltage	–22	22	–18	18	V
Differential Input Voltage	–38	38	–30	30	V
Input voltage Range ⁽³⁾					
Output Short Circuit Duration ⁽⁴⁾	Continuous		Continuous		
	TO Package		PDIP Package		
Power Dissipation ⁽⁵⁾	See ⁽⁶⁾		670		mW
T _j max	150		115		°C
Operating Temp. Range	See ⁽⁷⁾		See ⁽⁷⁾		
Lead Temp. (Soldering, 10 sec.)	260		260		°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Refer to RETS412X for LF412MH and LF412MJ military specifications.
- (3) Unless otherwise specified the absolute maximum negative input voltage is equal to the negative power supply voltage.
- (4) Any of the amplifier outputs can be shorted to ground indefinitely, however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.
- (5) Max. Power Dissipation is defined by the package characteristics. Operating the part near the Max. Power Dissipation may cause the part to operate outside guaranteed limits.
- (6) For operating at elevated temperature, these devices must be derated based on a thermal resistance of θ_{JA} .
- (7) These devices are available in both the commercial temperature range $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$ and the military temperature range $-55^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$. The temperature range is designated by the position just before the package type in the device number. A “C” indicates the commercial temperature range and an “M” indicates the military temperature range. The military temperature range is available in TO package only. In all cases the maximum operating temperature is limited by internal junction temperature T_j max.

6.2 Handling Ratings

			TO and PDIP Package		UNIT
			MIN	MAX	
T _{stg}	Storage temperature range		–65	150	°C
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	–1700	1700 ⁽²⁾	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽³⁾			

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) Human body model, 1.5 k Ω in series with 100 pF.
- (3) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply Voltage LF412A			±20	V
Supply Voltage LF412			±15	V

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TO Package	PDIP Package	UNIT
R _{θJA}	Junction-to-ambient thermal resistance (Typical)	152	115	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance			
R _{θJB}	Junction-to-board thermal resistance			
Ψ _{JT}	Junction-to-top characterization parameter			
Ψ _{JB}	Junction-to-board characterization parameter			
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance			

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 DC Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		LF412A ⁽¹⁾			LF412 ⁽¹⁾			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{OS}	Input Offset Voltage	R _S =10 kΩ, T _A =25°C			0.5	1.0		1.0	3.0	mV
ΔV _{OS} /ΔT	Average TC of Input Offset Voltage	R _S =10 kΩ			7			7		μV/°C
I _{OS}	Input Offset Current	V _S =±15V ⁽¹⁾⁽²⁾	T _J =25°C		25	100		25	100	pA
			T _J =70°C			2			2	nA
			T _J =125°C			25			25	nA
I _B	Input Bias Current	V _S =±15V ⁽¹⁾⁽²⁾	T _J =25°C		50	200		50	200	pA
			T _J =70°C			4			4	nA
			T _J =125°C			50			50	nA
R _{IN}	Input Resistance	T _J =25°C			10 ¹²			10 ¹²		Ω
A _{VOL}	Large Signal Voltage Gain	R _L =2k, T _A =25°C, V _S =±15V, V _O =±10V			50	200		25	200	V/mV
		Over Temperature			25	200		15	200	
V _O	Output Voltage Swing	V _S =±15V, R _L =10k		±12	±13.5		±12	±13.5		V
V _{CM}	Input Common-Mode Voltage Range			±16	+19.5		±11	+14.5		V
					-16.5			-11.5		V
CMRR	Common-Mode Rejection Ratio	R _S ≤10k			80	100		70	100	dB
PSRR	Supply Voltage Rejection Ratio	See ⁽³⁾			80	100		70	100	dB
I _S	Supply Current	V _O = 0V, R _L = ∞			3.6	5.6		3.6	6.5	mA

- (1) Unless otherwise specified, the specifications apply over the full temperature range and for V_S=±20V for the LF412A and for V_S=±15V for the LF412. V_{OS}, I_B, and I_{OS} are measured at V_{CM}=0.
- (2) The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature, T_J. Due to limited production test time, the input bias currents measured are correlated to junction temperature. In normal operation the junction temperature rises above the ambient temperature as a result of internal power dissipation, P_D. T_J=T_A+θ_{JA} P_D where θ_{JA} is the thermal resistance from junction to ambient. Use of a heat sink is recommended if input bias current is to be kept to a minimum.
- (3) Supply voltage rejection ratio is measured for both supply magnitudes increasing or decreasing simultaneously in accordance with common practice. V_S = ±6V to ±15V.

6.6 AC Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		LF412A ⁽¹⁾			LF412 ⁽¹⁾			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Amplifier to Amplifier Coupling		T _A =25°C, f=1 Hz-20 kHz (Input Referred)			-120			-120		dB

- (1) Unless otherwise specified, the specifications apply over the full temperature range and for V_S=±20V for the LF412A and for V_S=±15V for the LF412. V_{OS}, I_B, and I_{OS} are measured at V_{CM}=0.

LF412-N

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AC Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	LF412A ⁽¹⁾			LF412 ⁽¹⁾			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew Rate	$V_S = \pm 15V$, $T_A = 25^\circ C$	10	15		8	15		V/ μs
GBW	Gain-Bandwidth Product	$V_S = \pm 15V$, $T_A = 25^\circ C$	3	4		2.7	4		MHz
THD	Total Harmonic Dist	$A_V = +10$, $R_L = 10k$, $V_O = 20$ Vp-p, $BW = 20$ Hz-20 kHz	$\leq 0.02\%$			$\leq 0.02\%$			
e_n	Equivalent Input Noise Voltage	$T_A = 25^\circ C$, $R_S = 100\Omega$, $f = 1$ kHz	25			25			nV / $\sqrt{Hz}$
i_n	Equivalent Input Noise Current	$T_A = 25^\circ C$, $f = 1$ kHz	0.01			0.01			pA / $\sqrt{Hz}$

6.7 Typical Characteristics

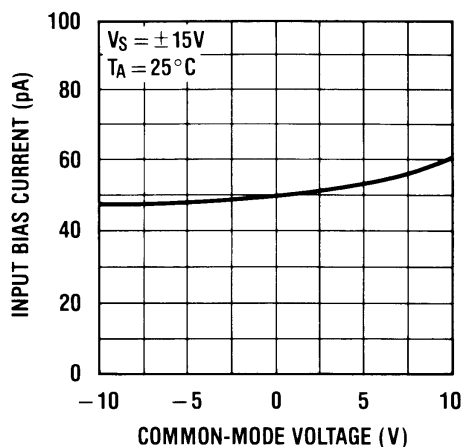


Figure 1. Input Bias Current

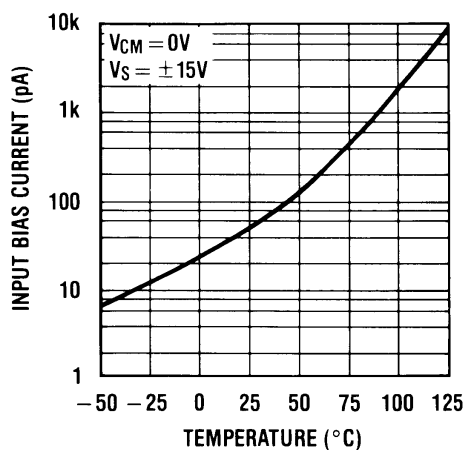


Figure 2. Input Bias Current

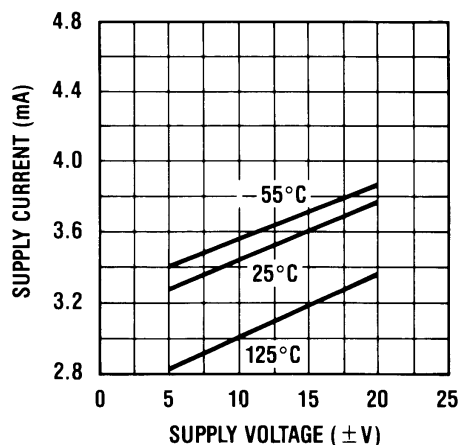


Figure 3. Supply Current

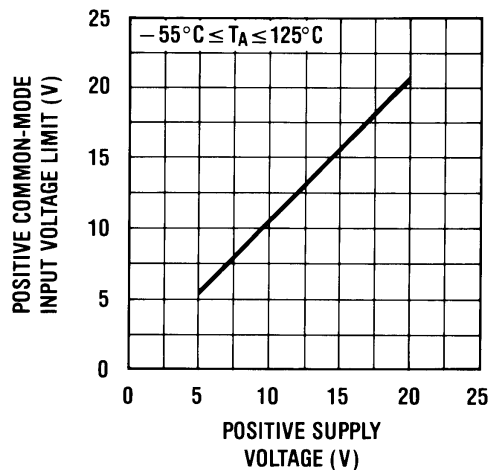


Figure 4. Positive Common-Mode Input Voltage Limit

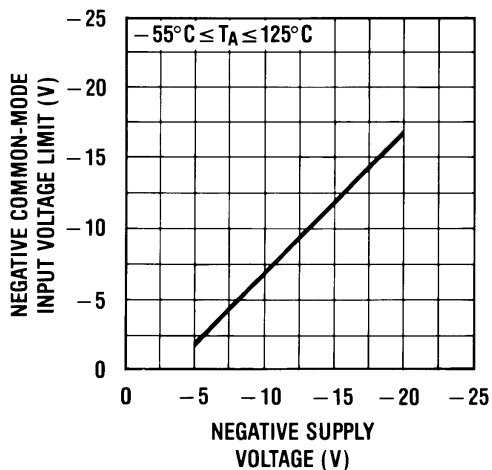


Figure 5. Negative Common-Mode Input Voltage Limit

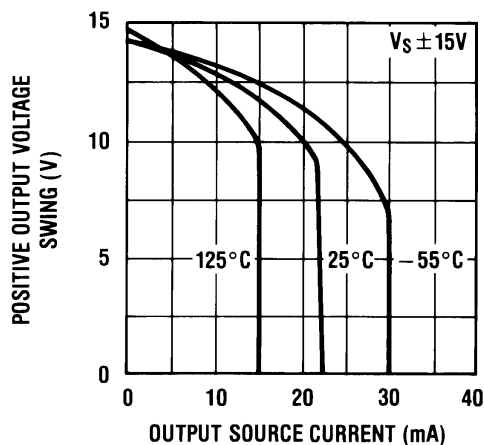


Figure 6. Positive Current Limit

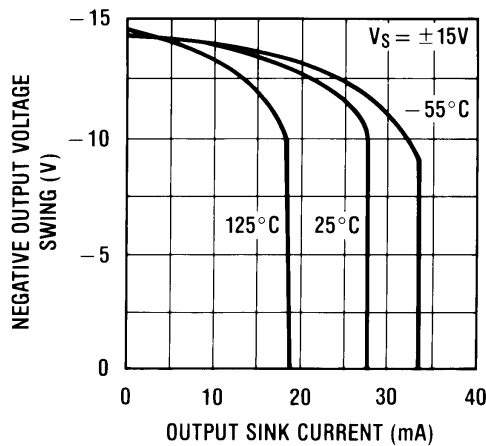
Typical Characteristics (continued)


Figure 7. Negative Current Limit

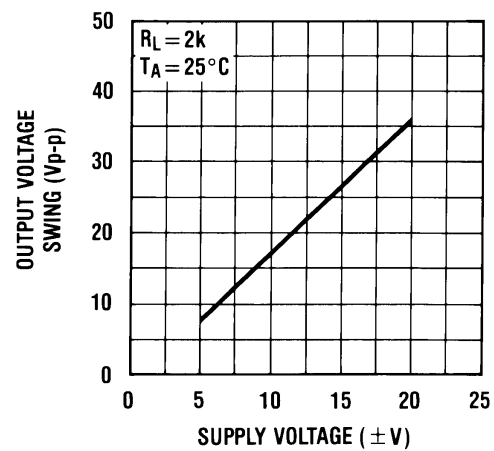


Figure 8. Output Voltage Swing

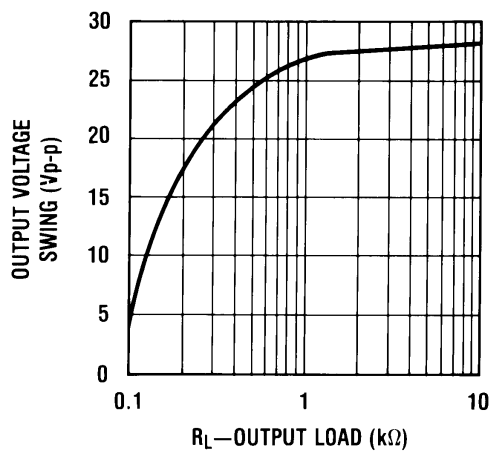


Figure 9. Output Voltage Swing

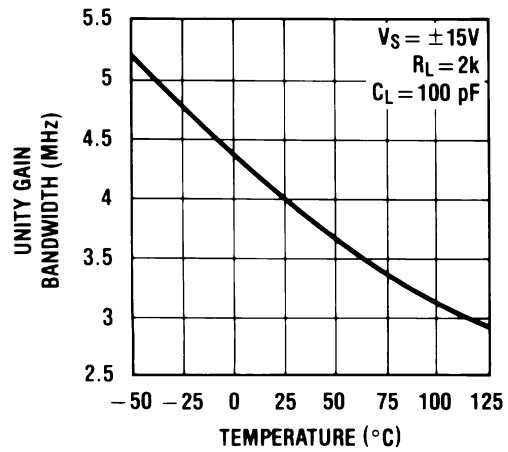


Figure 10. Gain Bandwidth

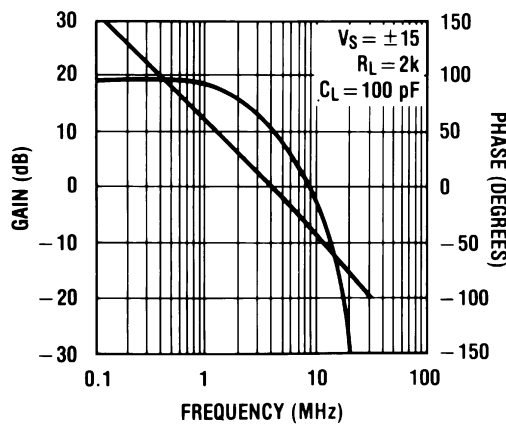


Figure 11. Bode Plot

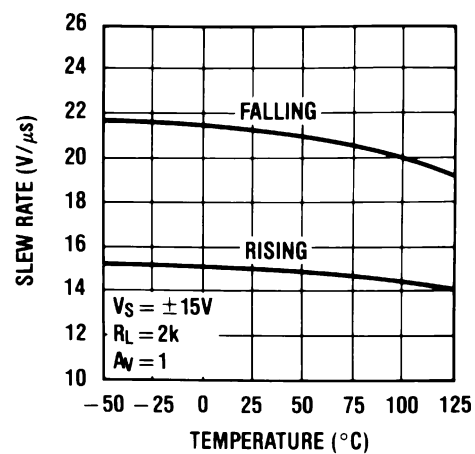


Figure 12. Slew Rate

Typical Characteristics (continued)

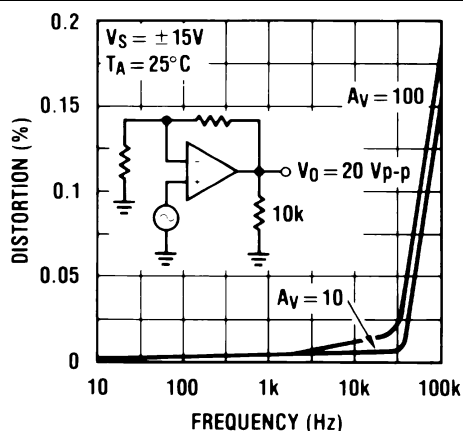


Figure 13. Distortion vs Frequency

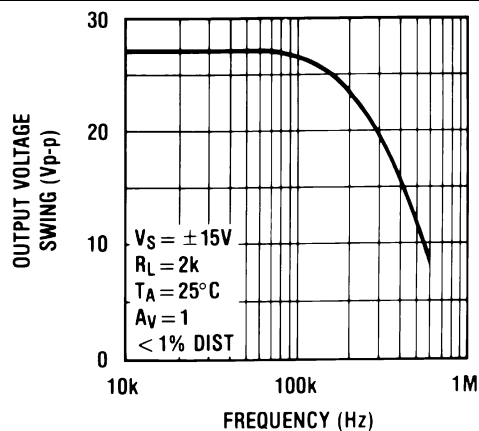


Figure 14. Undistorted Output Voltage Swing

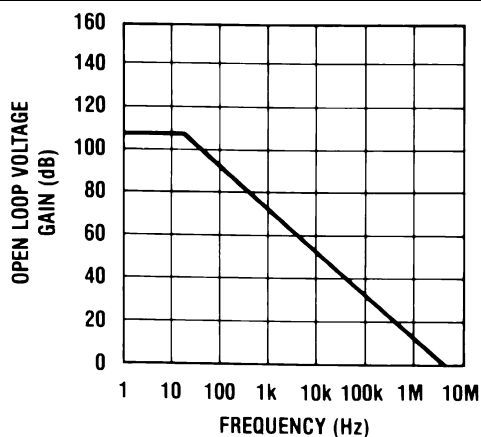


Figure 15. Open Loop Frequency Response

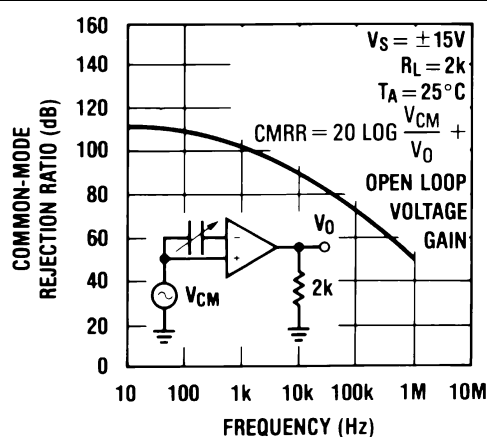


Figure 16. Common-Mode Rejection Ratio

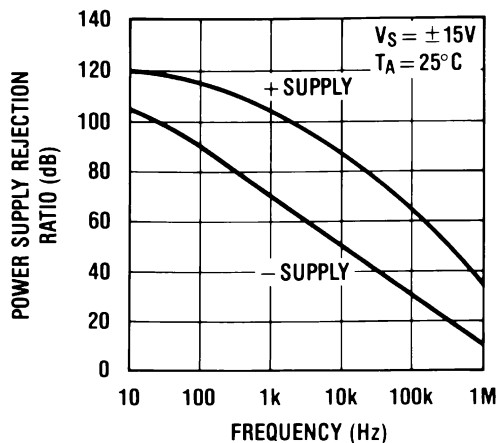


Figure 17. Power Supply Rejection Ratio

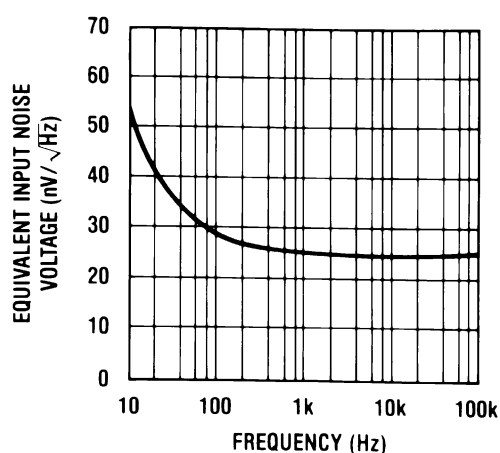


Figure 18. Equivalent Input Noise Voltage

Typical Characteristics (continued)

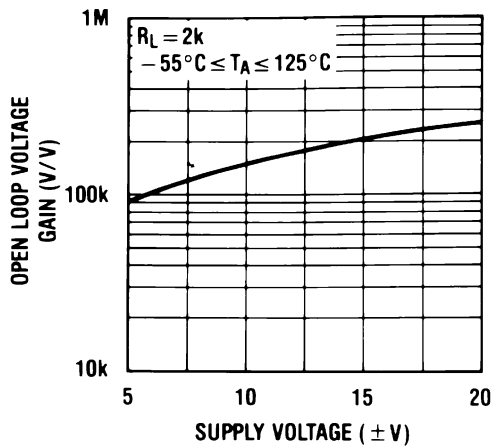


Figure 19. Open Loop Voltage Gain

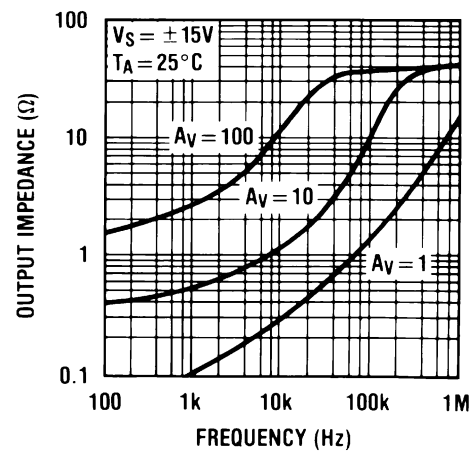


Figure 20. Output Impedance

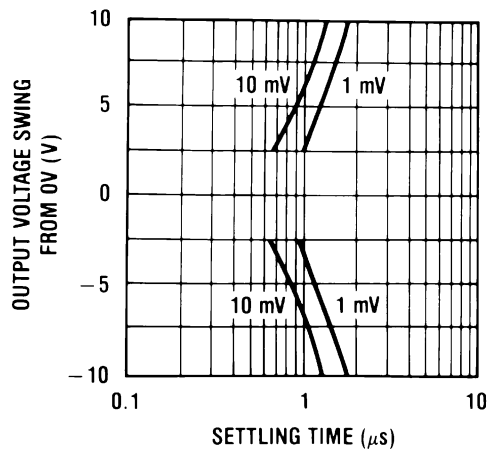


Figure 21. Inverter Settling Time

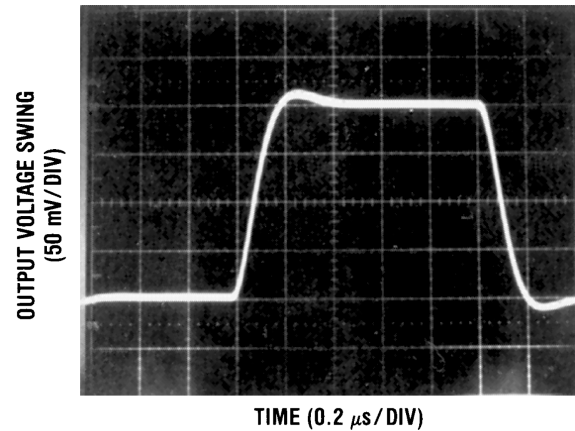


Figure 22. Small Signal Inverting
($R_L = 2\text{ k}\Omega$, $C_L = 10\text{ pF}$)

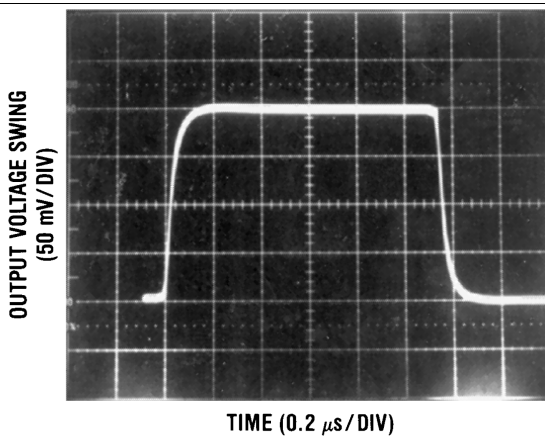


Figure 23. Small Signal Non-Inverting
($R_L = 2\text{ k}\Omega$, $C_L = 10\text{ pF}$)

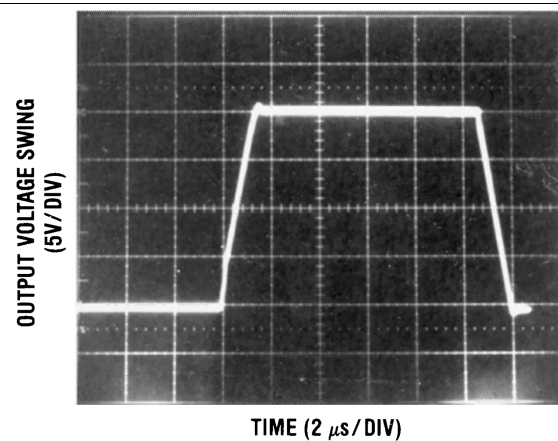


Figure 24. Large Signal Inverting
($R_L = 2\text{ k}\Omega$, $C_L = 10\text{ pF}$)

Typical Characteristics (continued)

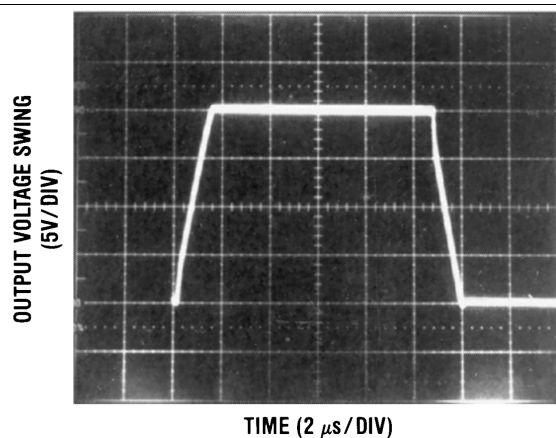


Figure 25. Large Signal Non-Inverting
($R_L = 2\text{ k}\Omega$, $C_L = 10\text{ pF}$)

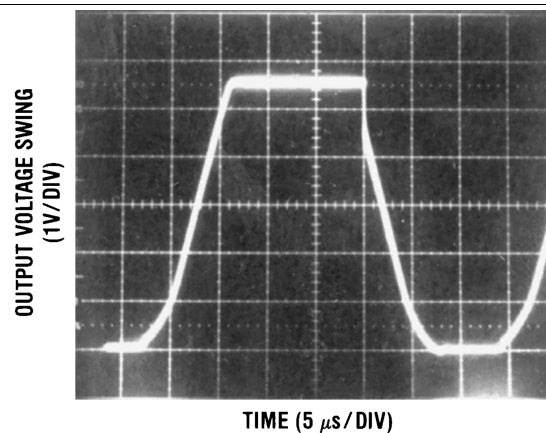


Figure 26. Current Limit ($R_L = 100\Omega$)
($C_L = 10\text{ pF}$)

7 Detailed Description

7.1 Overview

The LF412 devices are low cost, high speed, JFET input operational amplifiers with very low input offset voltage and input offset voltage drift. They require low supply current yet maintain a large gain bandwidth product and fast slew rate. In addition, well matched high voltage JFET input devices provide very low input bias and offset currents. The LF412-N dual is pin compatible with the LM1558, allowing designers to immediately upgrade the overall performance of existing designs.

These amplifiers may be used in applications such as high speed integrators, fast D/A converters, sample and hold circuits and many other circuits requiring low input offset voltage and drift, low input bias current, high input impedance, high slew rate and wide bandwidth.

7.2 Functional Block Diagram

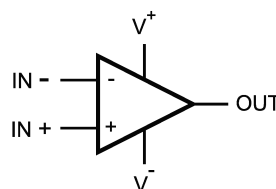


Figure 27. Each Amplifier

7.3 Feature Description

The amplifier's differential inputs consist of a non-inverting input (+IN) and an inverting input (-IN). The amplifier amplifies only the difference in voltage between the two inputs, which is called the differential input voltage. The output voltage of the op-amp V_{OUT} is given by the equation $V_{OUT} = A_{OL}(IN+ - IN-)$.

7.4 Device Functional Modes

7.4.1 Input and Output Stage

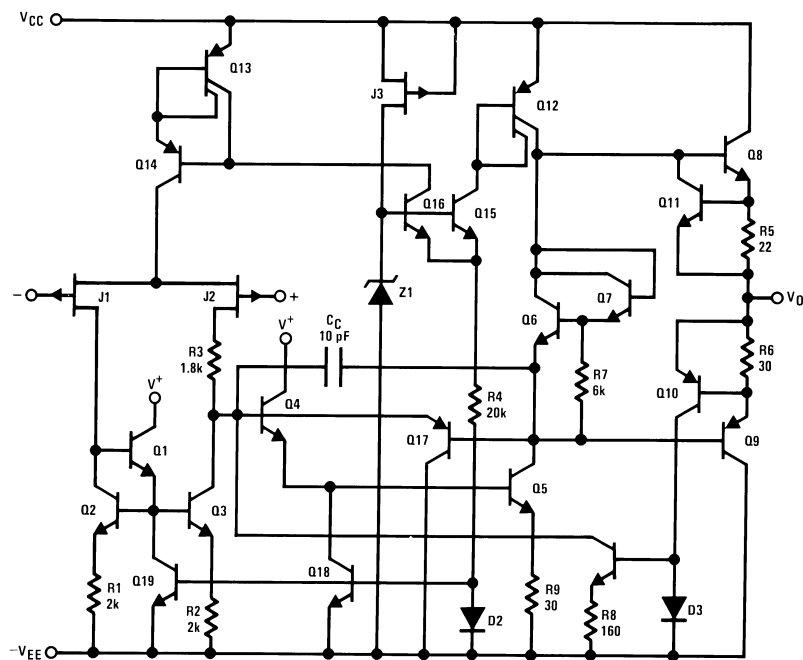


Figure 28. 1/2 Dual LF412

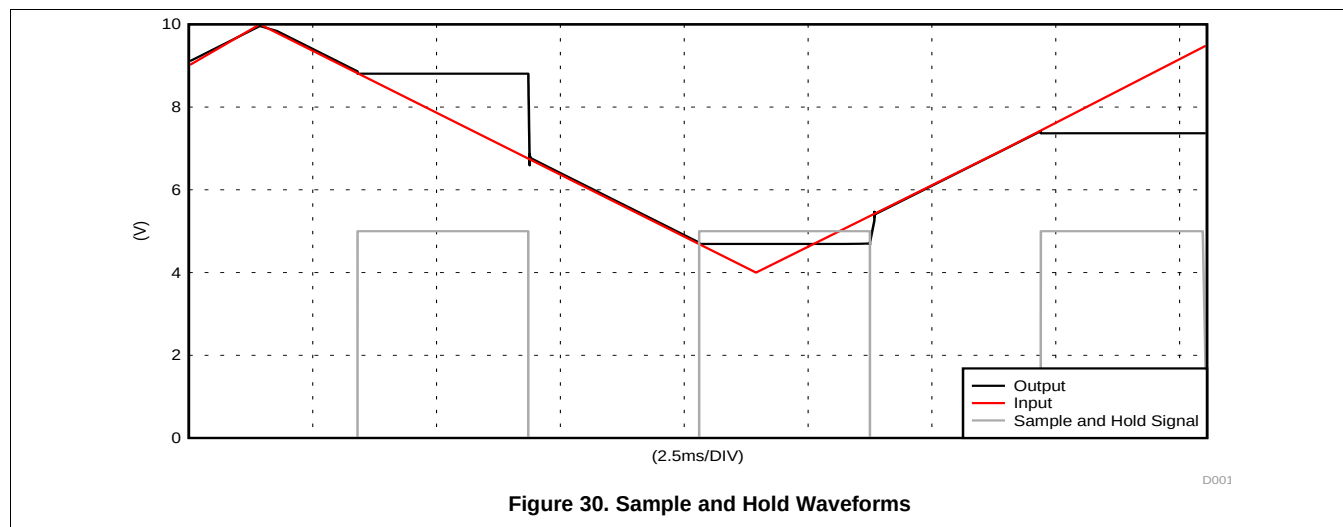
Typical Application (continued)

Precautions should be taken to ensure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

As with most amplifiers, care should be taken with lead dress, component placement and supply decoupling in order to ensure stability. For example, resistors from the output to an input should be placed with the body close to the input to minimize “pick-up” and maximize the frequency of the feedback pole by minimizing the capacitance from the input to ground.

A feedback pole is created when the feedback around any amplifier is resistive. The parallel resistance and capacitance from the input of the device (usually the inverting input) to AC ground set the frequency of the pole. In many instances the frequency of this pole is much greater than the expected 3 dB frequency of the closed loop gain and consequently there is negligible effect on stability margin. However, if the feedback pole is less than approximately 6 times the expected 3 dB frequency a lead capacitor should be placed from the output to the input of the op amp. The value of the added capacitor should be such that the RC time constant of this capacitor and the resistance it parallels is greater than or equal to the original feedback pole time constant.

8.2.3 Application Curves



9 Power Supply Recommendations

For proper operation, the power supplies must be properly decoupled. For decoupling the supply lines it is suggested that 0.1 μ F capacitors be placed as close as possible to the op amp power supply pins. The minimum power supply voltage is ± 5 V.

10 Layout

10.1 Layout Guidelines

As with most amplifiers, care should be taken with lead dress, component placement and supply decoupling in order to ensure stability. For example, resistors from the output to an input should be placed with the body close to the input to minimize “pick-up” and maximize the frequency of the feedback pole by minimizing the capacitance from the input to ground.

10.2 Layout Example

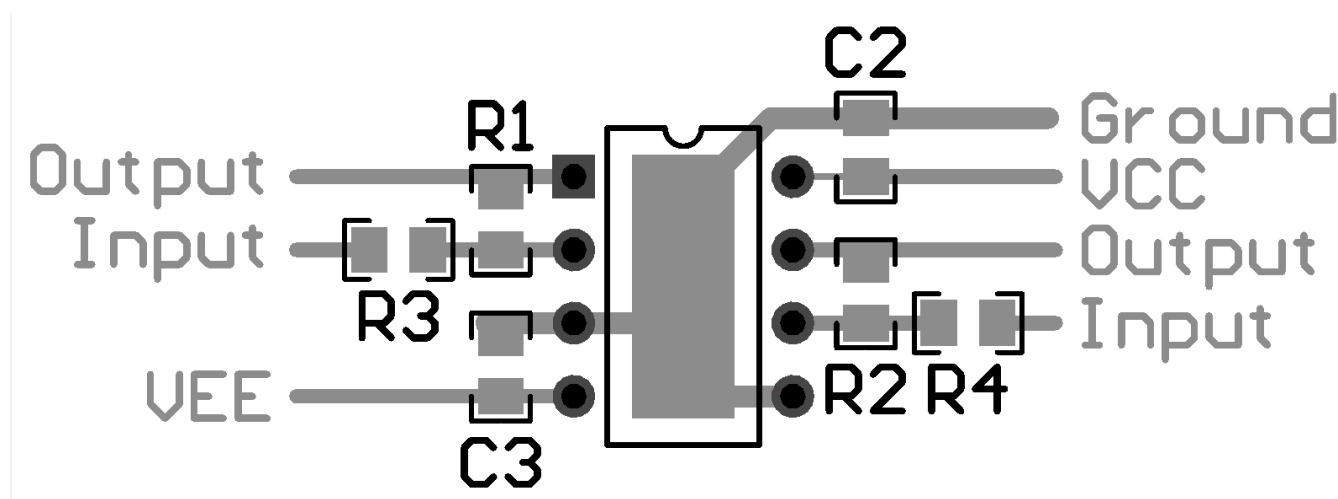


Figure 31. LF412 Layout

11 Device and Documentation Support

11.1 Trademarks

BI-FET II is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.3 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LF412ACN/NOPB	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412ACN
LF412ACN/NOPB.B	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412ACN
LF412ACN/NOPBG4	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412ACN
LF412ACN/NOPBG4.B	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412ACN
LF412CN/NOPB	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412CN
LF412CN/NOPB.B	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412CN
LF412CN/NOPBG4	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412CN
LF412CN/NOPBG4.B	Active	Production	PDIP (P) 8	40 TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	0 to 70	LF 412CN

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

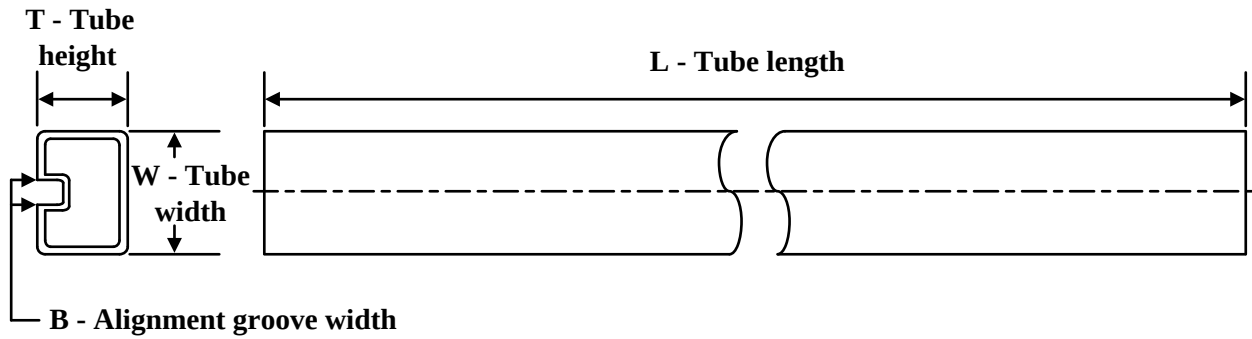
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TUBE

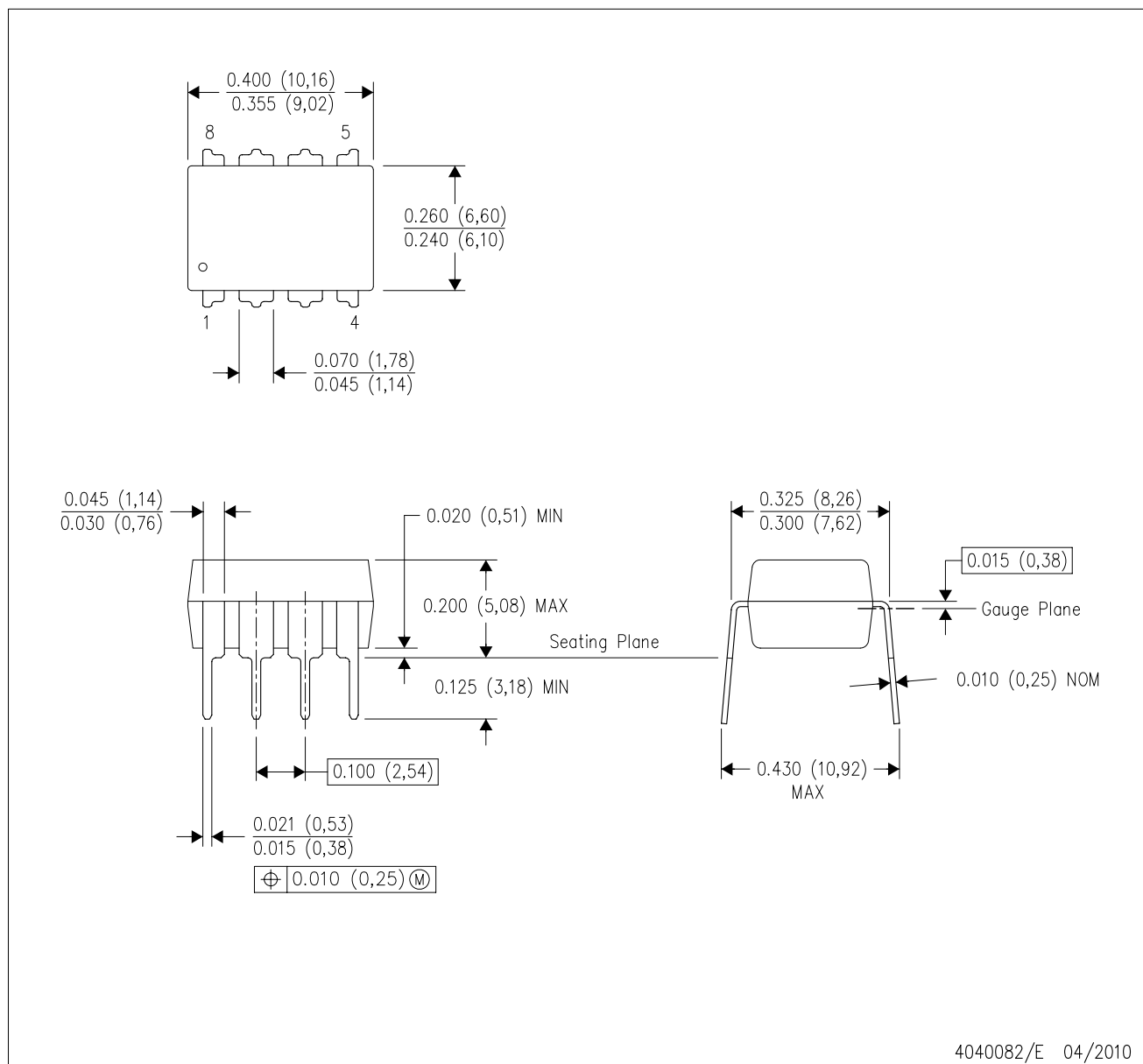


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LF412ACN/NOPB	P	PDIP	8	40	502	14	11938	4.32
LF412ACN/NOPB.B	P	PDIP	8	40	502	14	11938	4.32
LF412ACN/NOPBG4	P	PDIP	8	40	502	14	11938	4.32
LF412ACN/NOPBG4.B	P	PDIP	8	40	502	14	11938	4.32
LF412CN/NOPB	P	PDIP	8	40	502	14	11938	4.32
LF412CN/NOPB.B	P	PDIP	8	40	502	14	11938	4.32
LF412CN/NOPBG4	P	PDIP	8	40	502	14	11938	4.32
LF412CN/NOPBG4.B	P	PDIP	8	40	502	14	11938	4.32

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

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Last updated 10/2025